

# **BC858B-QVL Datasheet**



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DiGi Electronics Part Number BC858B-QVL-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC858B-QVL

Description TRANS PNP 30V 0.1A TO236AB

**Detailed Description** Bipolar (BJT) Transistor PNP 30 V 100 mA 100MHz 2

50 mW Surface Mount TO-236AB



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### **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
BC858B-QVL	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
30 V	650mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
15nA (ICBO)	220 @ 2mA, 5V
Power - Max:	Frequency - Transition:
250 mW	100MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	TO-236AB
Base Product Number:	
BC858	

### **Environmental & Export classification**

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



### 65 V, 100 mA PNP general-purpose transistors

Rev. 2 — 21 February 2022

**Product data sheet** 

### 1. General description

PNP general-purpose transistors in a small SOT23 (TO-236AB), Surface-Mounted Device (SMD) plastic package.

**Table 1. Product overview** 

Type number	Package		NPN complement
	Nexperia	JEDEC	
BC856-Q	SOT23	TO-236AB	BC846-Q
BC856A-Q			BC846A-Q
BC856B-Q			BC846B-Q
BC857-Q			BC847-Q
BC857A-Q			BC847A-Q
BC857B-Q			BC847B-Q
BC857C-Q			BC847C-Q
BC858B-Q			BC848B-Q

#### 2. Features and benefits

- Low current (max. 100 mA)
- Low voltage (max. 65 V)
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

### 3. Applications

· General-purpose switching and amplification



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#### 4. Quick reference data

#### Table 2. Quick reference data

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base				_
	BC856-Q; BC856A-Q; BC856B-Q		-	-	-65	V
	BC857-Q; BC857A-Q; BC857B-Q; BC857C-Q		-	-	-45	V
	BC858B-Q		-	-	-30	V
I <sub>C</sub>	collector current		-	-	-100	mA
I <sub>CM</sub>	peak collector current		-	-	-200	mA
h <sub>FE</sub>	DC current gain					
	BC856-Q		125	-	475	
	BC857-Q		125	-	800	
	BC856A-Q; BC857A-Q	$V_{CF} = 5 \text{ V; } I_{C} = 2 \text{ mA}$	125	-	250	
	BC856B-Q; BC857B-Q; BC858B-Q	v CE - 3 v, IC - 2 IIIA	220	-	475	
	BC857C-Q		420	-	800	

### 5. Pinning information

**Table 3. Pinning information** 

Pin	Symbol	Descrition	Simlified outline	Graphic symbol
1	В	base	]3	C
2	E	emitter		R_
3	С	collector		, h
				E
			1 2	sym132

### 6. Ordering information

**Table 4. Ordering information** 

Type number	Package						
	Name	Description	Version				
BC856-Q	TO-236AB	plastic surface-mounted package; 3 leads	SOT23				
BC856A-Q							
BC856B-Q							
BC857-Q							
BC857A-Q							
BC857B-Q							
BC857C-Q							
BC858B-Q							

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### 7. Marking

Table 5. Marking codes

Type number		Marking code
BC856-Q	[1]	3D%
BC856A-Q	[1]	3A%
BC856B-Q	[1]	3B%
BC857-Q	[1]	3H%
BC857A-Q	[1]	3E%
BC857B-Q	[1]	3F%
BC857C-Q	[1]	3G%
BC858B-Q	[1]	3K%

<sup>[1] % =</sup> placeholder for manufacturing site code

### 8. Limiting values

#### **Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter				
	BC856-Q; BC856A-Q; BC856B-Q			-	-80	V
	BC857-Q; BC857A-Q; BC857B-Q; BC857C-Q			-	-50	V
	BC858B-Q			-	-30	V
V <sub>CEO</sub>	collector-emitter voltage	open base				
	BC856-Q; BC856A-Q; BC856B-Q			-	-65	V
	BC857-Q; BC857A-Q; BC857B-Q; BC857C-Q			-	-45	V
	BC858B-Q			-	-30	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-100	mA
I <sub>CM</sub>	peak collector current			-	-200	mA
I <sub>BM</sub>	peak base current			-	-200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	250	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.

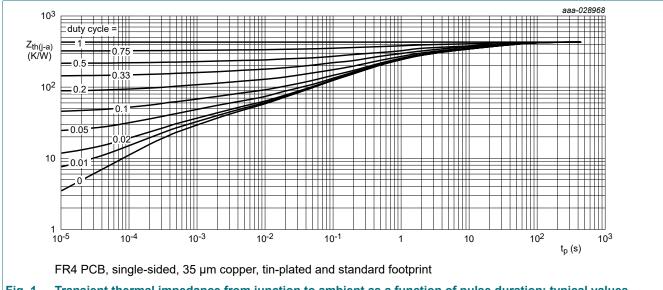
65 V, 100 mA PNP general-purpose transistors

#### 9. Thermal characteristics

**Table 7. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
· ·ui(y-a)	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB; single-sided, 35 µm copper; tin-plated and standard footprint.



Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig. 1.

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#### 10. Characteristics

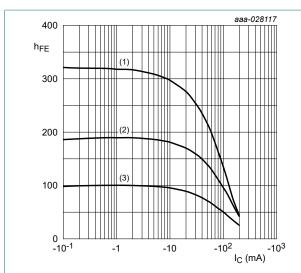
#### **Table 8. Characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	collector-base breakdow	vn voltage					
	BC856-Q; BC856A-Q; BC856B-Q	·		-80	-	-	V
BC857-Q; BC857A-Q; BC857B-Q; BC857C-Q		I <sub>C</sub> = -100 μA; I <sub>E</sub> = 0 A		-50	-	-	V
	BC858B-Q			-30	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdo	own voltage					
	BC856-Q; BC856A-Q; BC856B-Q			-65	-	-	V
	BC857-Q; BC857A-Q; BC857B-Q; BC857C-Q	$I_{C} = -2 \text{ mA}; I_{B} = 0 \text{ A}$		-45	-	-	V
	BC858B-Q			-30	-	-	V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage	I <sub>C</sub> = 0 A; I <sub>E</sub> = -100 μA		-5	-	-	V
I <sub>CBO</sub> collector-base		V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A		-	-1	-15	nA
	cut-off current	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-4	μA
ЕВО	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A		-	-	-100	nA
h <sub>FE</sub>	DC current gain						
	BC856-Q			125	-	475	
	BC857-Q			125	-	800	
	BC856A-Q; BC857A-Q	$V_{CF} = -5 \text{ V; } I_{C} = -2 \text{ mA}$		125	-	250	
BC856B-Q; BC857B-Q; BC858B-Q		VCE0 V, IC2 IIIA		220	-	475	
	BC857C-Q			420	-	800	
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = -10 mA; I <sub>B</sub> = -0.5 mA		-	-75	-300	mV
	saturation voltage	I <sub>C</sub> = -100 mA; I <sub>B</sub> = -5 mA	[1]	-	-250	-650	mV
V <sub>BEsat</sub>	base-emitter saturation	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	[1]	-	-700	-	mV
	voltage	I <sub>C</sub> = -100 mA; I <sub>B</sub> = -5 mA	[1]	-	-850	-	mV
V <sub>BE</sub>	base-emitter voltage	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -2 mA		-600	-650	-750	mV
		V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA		-	-	-820	mV
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	4.5	-	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA; f = 100 MHz		100	-	-	MHz
NF	noise figure	$I_C$ = -200 μA; $V_{CE}$ = -5 V; $R_S$ = 2 kΩ; $f$ = 1 kHz; $B$ = 200Hz		-	2	10	dB

<sup>[1]</sup> pulsed;  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

#### 65 V, 100 mA PNP general-purpose transistors



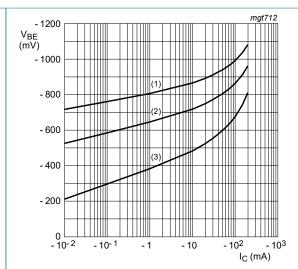
$$V_{CE} = -5 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55$$
 °C

Fig. 2. BC856A-Q; BC857A-Q: DC current gain as a function of collector current; typical values



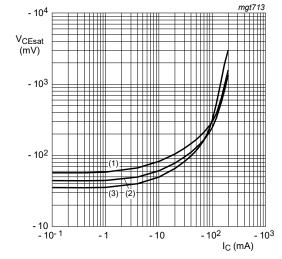
$$V_{CE} = -5 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 3. BC856A-Q; BC857A-Q: Base-emitter voltage as a function of collector current; typical values



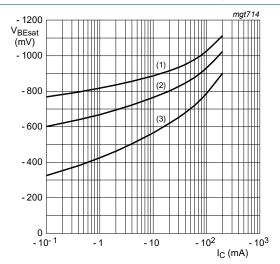
$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 150 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC856A-Q; BC857A-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = -55$$
 °C

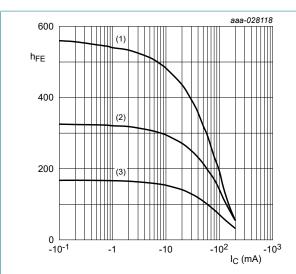
(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC856A-Q; BC857A-Q: Base-emitter saturation voltage as a function of collector current; typical values

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#### 65 V, 100 mA PNP general-purpose transistors



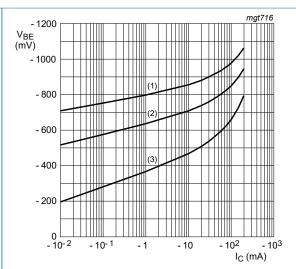
$$V_{CE} = -5 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55$$
 °C

Fig. 6. BC856B-Q; BC857B-Q; BC858B-Q: DC current gain as a function of collector current; typical values



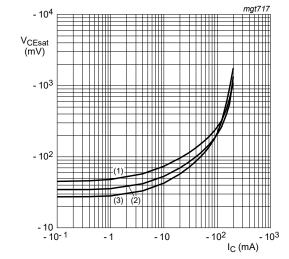
$$V_{CE} = -5 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 7. BC856B-Q; BC857B-Q; BC858B-Q: Base-emitter voltage as a function of collector current; typical values



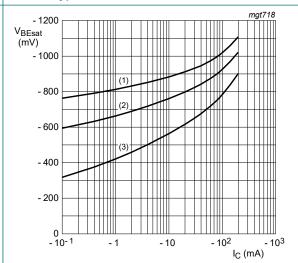
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55$$
 °C

Fig. 8. BC856B-Q; BC857B-Q; BC858B-Q: Collectoremitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

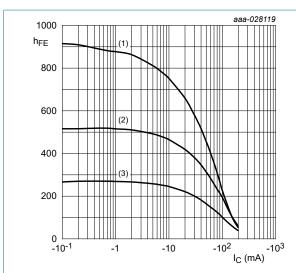
(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 9. BC856B-Q; BC857B-Q; BC858B-Q: Base-emitter saturation voltage as a function of collector current; typical values

#### 65 V, 100 mA PNP general-purpose transistors



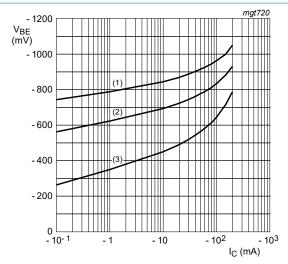
$$V_{CE} = -5 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. BC857C-Q: DC current gain as a function of collector current; typical values



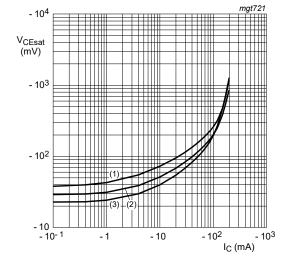
$$V_{CE} = -5 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 11. BC857C-Q: Base-emitter voltage as a function of collector current; typical values

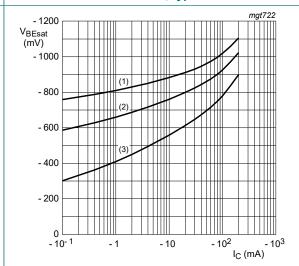


$$I_C/I_B = 20$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 12. BC857C-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

Fig. 13. BC857C-Q: Base-emitter saturation voltage as a function of collector current; typical values

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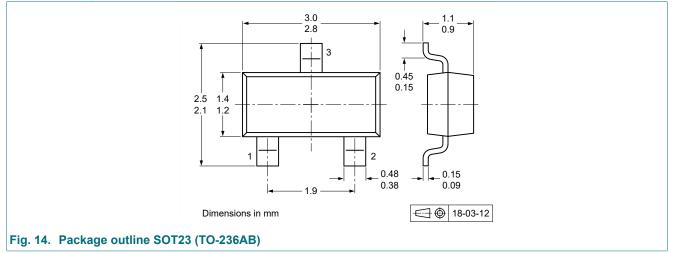
#### 11. Test information

#### 11.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

### 12. Package outline

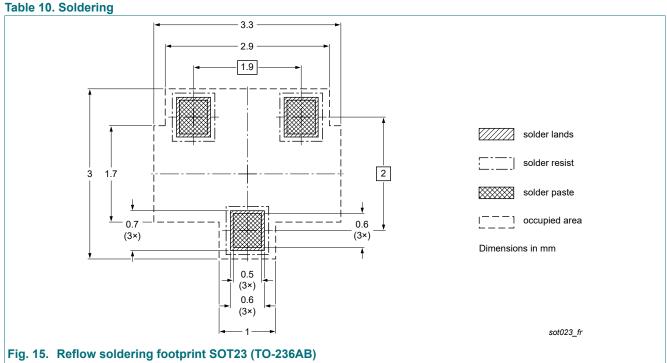
#### Table 9. Package outline

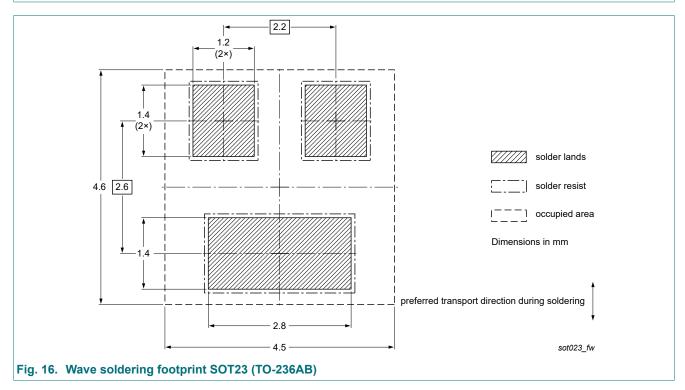


65 V, 100 mA PNP general-purpose transistors

### 13. Soldering







65 V, 100 mA PNP general-purpose transistors

### 14. Revision history

#### **Table 11. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BC856-Q_BC857-Q_BC858-Q v.2	20220221	Product data sheet	-	BC856-Q_BC857-Q_BC858-Q v.1	
Modifications:	<ul> <li>Quick reference data: BC856-Q corrected to BC856B-Q at h<sub>FE</sub></li> <li>Limiting values and Characteristics: Product names changed to detailed descriptions</li> </ul>				
BC856-Q_BC857-Q_BC858-Q v.1	20210624	Product data sheet	-	-	

#### 65 V, 100 mA PNP general-purpose transistors

#### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### **Nexperia**

### BC856-Q; BC857-Q; BC858-Q

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For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 21 February 2022

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